1. General description

The 74AUP2G126 is a dual buffer/line driver with 3-state outputs controlled by the output enable inputs (nOE). Schmitt-trigger action at all inputs makes the circuit tolerant of slower input rise and fall times. This device ensures very low static and dynamic power consumption across the entire V_{CC} range from 0.8 V to 3.6 V.

This device is fully specified for partial power down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the potentially damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 0.8 V to 3.6 V
- · High noise immunity
- · CMOS low power dissipation
- Low static power consumption; I_{CC} = 0.9 μA (maximum)
- Latch-up performance exceeds 100 mA per JESD78 Class II
- Overvoltage tolerant inputs to 3.6 V
- Low noise overshoot and undershoot < 10 % of V_{CC}
- · Input-disable feature allows floating input conditions
- I_{OFF} circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 100 mA per JESD 78 Class II Level B
- Complies with JEDEC standards:
 - JESD8-12 (0.8 V to 1.3 V)
 - JESD8-11 (0.9 V to 1.65 V)
 - JESD8-7 (1.2 V to 1.95 V)
 - JESD8-5 (1.8 V to 2.7 V)
 - JESD8C (2.7 V to 3.6 V)
- · ESD protection:
 - HBM: ANSI/ESDA/JEDEC JS-001 class 3A exceeds 5000 V
 - CDM: ANSI/ESDA/JEDEC JS-002 class C3 exceeds 1000 V
- Multiple package options
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



Low-power dual buffer/line driver; 3-state

3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AUP2G126DC	-40 °C to +125 °C	VSSOP8	plastic very thin shrink small outline package; 8 leads; body width 2.3 mm	SOT765-1
74AUP2G126GT	-40 °C to +125 °C	XSON8	plastic extremely thin small outline package; no leads; 8 terminals; body 1 × 1.95 × 0.5 mm	SOT833-1
74AUP2G126GN	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.2 × 1.0 × 0.35 mm	SOT1116
74AUP2G126GS	-40 °C to +125 °C	XSON8	extremely thin small outline package; no leads; 8 terminals; body 1.35 × 1.0 × 0.35 mm	SOT1203
74AUP2G126GX	-40 °C to +125 °C	X2SON8	plastic thermal enhanced extremely thin small outline package; no leads; 8 terminals; body 1.35 × 0.8 × 0.32 mm	SOT1233-2

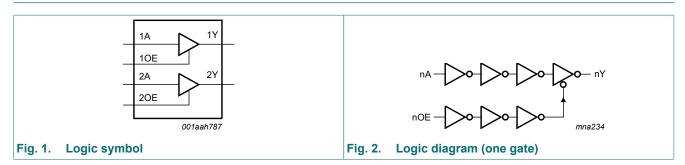
4. Marking

Table 2. Marking codes

Type number	Marking code[1]					
74AUP2G126DC	p26					
74AUP2G126GT	p26					
74AUP2G126GN	pN					
74AUP2G126GS	pN					
74AUP2G126GX	pN					

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

5. Functional diagram



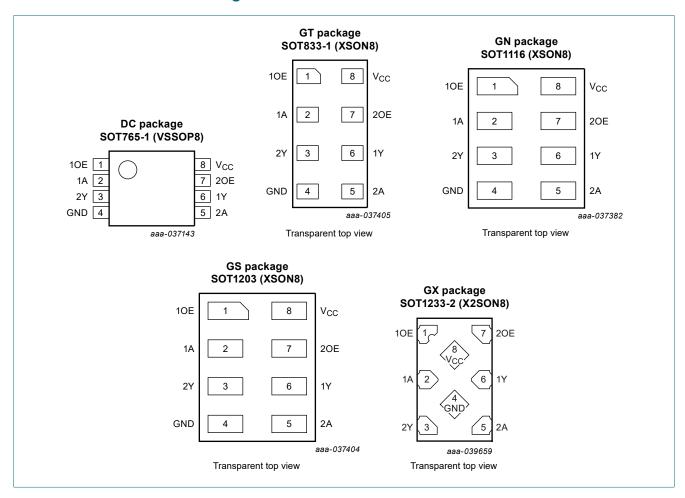
Product data sheet

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6. Pinning information

6.1. Pinning



6.2. Pin description

Table 3. Pin description

Table of the accompany								
Symbol	Pin	Description						
10E, 20E	1, 7	output enable input (active HIGH)						
1A, 2A	2, 5	data input						
1Y, 2Y	6, 3	data output						
GND	4	ground (0 V)						
V _{CC}	8	supply voltage						

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7. Functional description

Table 4. Function table

 $H = HIGH \text{ voltage level}; L = LOW \text{ voltage level}; X = don't care; Z = high-impedance OFF-state.}$

Input nOE		Output
nOE	nA	nY
Н	L	L
Н	Н	Н
L	X	Z

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+4.6	V
I _{IK}	input clamping current	V _I < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+4.6	V
lok	output clamping current	V _O < 0 V		-50	-	mA
Vo	output voltage	Active mode and Power-down mode	[1]	-0.5	+4.6	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$		-	±20	mA
I _{CC}	supply current			-	+50	mA
I _{GND}	ground current			-50	-	mA
T _{stg}	storage temperature			-65	+150	°C
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C				
		SOT765-1 (VSSOP8) SOT833-1 (XSON8) SOT1116 (XSON8) SOT1203 (XSON8)	[2]	-	250	mW
		SOT1233-2 (X2SON8)	[3]	-	300	mW

^[1] The minimum input and output voltage ratings may be exceeded if the input and output current ratings are observed.

9. Recommended operating conditions

Table 6. Operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		0.8	3.6	V
VI	input voltage		0	3.6	V
Vo	output voltage	Active mode	0	V _{CC}	V
		Power-down mode; V _{CC} = 0 V	0	3.6	V
T _{amb}	ambient temperature		-40	+125	°C
Δt/ΔV	input transition rise and fall rate	V _{CC} = 0.8 V to 3.6 V	0	200	ns/V

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^[2] For SOT765-1 (VSSOP8) package: P_{tot} derates linearly with 4.9 mW/K above 99 °C. For SOT833-1 (XSON8) package: P_{tot} derates linearly with 3.1 mW/K above 68 °C. For SOT1116 (XSON8) package: P_{tot} derates linearly with 4.2 mW/K above 90 °C. For SOT1203 (XSON8) package: P_{tot} derates linearly with 3.6 mW/K above 81 °C.

^[3] For SOT1233-2 (X2SON8) package: Ptot derates linearly with 7.7 mW/K above 118 °C.

Low-power dual buffer/line driver; 3-state

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = 2	25 °C		'			
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}				
		$I_O = -20 \mu A$; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.75 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	1.11	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.32	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	2.05	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.9	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.72	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.6	-	-	V
V _{OL} I	LOW-level output voltage	V _I = V _{IH} or V _{IL}				
		$I_O = 20 \mu A$; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$	-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.31	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.31	V
		I _O = 2.3 mA; V _{CC} = 2.3 V	-	-	0.31	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.44	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.31	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.44	V
I _I	input leakage current	V_{I} = GND to 3.6 V; V_{CC} = 0 V to 3.6 V	-	-	±0.1	μA
l _{OZ}	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_O = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V to } 3.6 \text{ V}$	-	-	±0.1	μΑ
I _{OFF}	power-off leakage current	V_{I} or $V_{O} = 0 \text{ V}$ to 3.6 V; $V_{CC} = 0 \text{ V}$	-	-	±0.2	μΑ
Δl _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.2	μΑ
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V	-	-	0.5	μA
ΔI _{CC}	additional supply current	data input; $V_I = V_{CC}$ - 0.6 V; $I_O = 0$ A; $V_{CC} = 3.3$ V	[1] -	-	40	μA
		nOE input; $V_I = V_{CC}$ - 0.6 V; $I_O = 0$ A; $V_{CC} = 3.3$ V	[1] -	-	110	μΑ
		all inputs; V_1 = GND to 3.6 V; nOE = GND; V_{CC} = 0.8 V to 3.6 V	[2] -	-	1	μΑ

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Cı	input capacitance	V_I = GND or V_{CC} ; V_{CC} = 0 V to 3.6 V		-	0.9	-	pF
Co	output capacitance	output enabled; V _O = GND; V _{CC} = 0 V		-	1.7	-	pF
		output disabled; V _O = GND or V _{CC} ; V _{CC} = 0 V to 3.6 V		-	1.5	-	pF
T _{amb} = -	40 °C to +85 °C						
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V		0.70 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V		0.65 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V		1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V		2.0	-	-	V
V _{IL}	LOW-level input voltage	$V_{CC} = 0.8 \text{ V}$		-	-	0.30 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V		-	-	0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V		-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V		-	-	0.9	V
V _{OH}	HIGH-level output voltage	V _I = V _{IH} or V _{IL}					
		$I_O = -20 \mu A$; $V_{CC} = 0.8 \text{ V to } 3.6 \text{ V}$		V _{CC} - 0.1	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V		0.7 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V		1.03	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V		1.30	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V		1.97	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V		1.85	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V		2.67	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V		2.55	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}					+
		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V		-	-	0.1	V
		I _O = 1.1 mA; V _{CC} = 1.1 V		-	-	0.3 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V		-	-	0.37	V
		I _O = 1.9 mA; V _{CC} = 1.65 V		-	_	0.35	V
		$I_{O} = 2.3 \text{ mA}; V_{CC} = 2.3 \text{ V}$		-	-	0.33	V
		I _O = 3.1 mA; V _{CC} = 2.3 V		-	-	0.45	V
		I _O = 2.7 mA; V _{CC} = 3.0 V		-	-	0.33	V
		I _O = 4.0 mA; V _{CC} = 3.0 V		-	_	0.45	V
l _l	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V		-	-	±0.5	μA
l _{OZ}	OFF-state output current	$V_I = V_{IH} \text{ or } V_{IL}; V_O = 0 \text{ V to } 3.6 \text{ V};$ $V_{CC} = 0 \text{ V to } 3.6 \text{ V}$		-	-	±0.5	μA
I _{OFF}	power-off leakage current	V_1 or $V_0 = 0$ V to 3.6 V; $V_{CC} = 0$ V		-	_	±0.5	μA
Δl _{OFF}	additional power-off leakage current	V ₁ or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V		-	-	±0.6	μA
I _{CC}	supply current	V _I = GND or V _{CC} ; I _O = 0 A; V _{CC} = 0.8 V to 3.6 V		-	-	0.9	μA
ΔI _{CC}	additional supply current		[1]	-	-	50	μA
		nOE input; V _I = V _{CC} - 0.6 V; I _O = 0 A; V _{CC} = 3.3 V	[1]	-	-	120	μA
		all inputs; V_I = GND to 3.6 V; nOE = GND; V_{CC} = 0.8 V to 3.6 V	[2]	-	-	1	μA

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb} = -	40 °C to +125 °C			1		
V _{IH}	HIGH-level input voltage	V _{CC} = 0.8 V	0.75 × V _{CC}	-	-	V
		V _{CC} = 0.9 V to 1.95 V	0.70 × V _{CC}	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.6	-	-	V
		V _{CC} = 3.0 V to 3.6 V	2.0	-	-	V
V _{IL}	LOW-level input voltage	V _{CC} = 0.8 V	-	-	0.25 × V _{CC}	V
		V _{CC} = 0.9 V to 1.95 V	-	-	0.30 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V _{CC} = 3.0 V to 3.6 V	-	-	0.9	V
V _{OH}	HIGH-level output voltage					
		I _O = -20 μA; V _{CC} = 0.8 V to 3.6 V	V _{CC} - 0.11	-	-	V
		I _O = -1.1 mA; V _{CC} = 1.1 V	0.6 × V _{CC}	-	-	V
		I _O = -1.7 mA; V _{CC} = 1.4 V	0.93	-	-	V
		I _O = -1.9 mA; V _{CC} = 1.65 V	1.17	-	-	V
		I _O = -2.3 mA; V _{CC} = 2.3 V	1.77	-	-	V
		I _O = -3.1 mA; V _{CC} = 2.3 V	1.67	-	-	V
		I _O = -2.7 mA; V _{CC} = 3.0 V	2.40	-	-	V
		I _O = -4.0 mA; V _{CC} = 3.0 V	2.30	-	-	V
V _{OL}	LOW-level output voltage	$V_I = V_{IH}$ or V_{IL}				
-		I _O = 20 μA; V _{CC} = 0.8 V to 3.6 V	-	-	0.11	V
		I _O = 1.1 mA; V _{CC} = 1.1 V	-	-	0.33 × V _{CC}	V
		I _O = 1.7 mA; V _{CC} = 1.4 V	-	-	0.41	V
		I _O = 1.9 mA; V _{CC} = 1.65 V	-	-	0.39	V
		I_{O} = 2.3 mA; V_{CC} = 2.3 V	-	-	0.36	V
		I _O = 3.1 mA; V _{CC} = 2.3 V	-	-	0.50	V
		I _O = 2.7 mA; V _{CC} = 3.0 V	-	-	0.36	V
		I _O = 4.0 mA; V _{CC} = 3.0 V	-	-	0.50	V
I _I	input leakage current	V _I = GND to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.75	μA
l _{OZ}	OFF-state output current	V _I = V _{IH} or V _{IL} ; V _O = 0 V to 3.6 V; V _{CC} = 0 V to 3.6 V	-	-	±0.75	μA
I _{OFF}	power-off leakage current	V_1 or $V_0 = 0 \text{ V to } 3.6 \text{ V}; V_{CC} = 0 \text{ V}$	-	-	±0.75	μA
ΔI _{OFF}	additional power-off leakage current	V _I or V _O = 0 V to 3.6 V; V _{CC} = 0 V to 0.2 V	-	-	±0.75	μA
I _{CC}	supply current	V_1 = GND or V_{CC} ; I_0 = 0 A; V_{CC} = 0.8 V to 3.6 V	-	-	1.4	μA
ΔI _{CC}	additional supply current	data input; $V_I = V_{CC} - 0.6 \text{ V}$; $I_O = 0 \text{ A}$; $V_{CC} = 3.3 \text{ V}$	-	-	75	μA
		nOE input; $V_I = V_{CC} - 0.6 \text{ V}$; $I_O = 0 \text{ A}$; $I_{CC} = 3.3 \text{ V}$	-	-	180	μA
		all inputs; V_I = GND to 3.6 V; nOE = GND; V_{CC} = 0.8 V to 3.6 V	2] -	-	1	μA

One input at V_{CC} - 0.6 V, other input at V_{CC} or GND. To show I_{CC} remains very low when the input-disable feature is enabled.

Low-power dual buffer/line driver; 3-state

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Fig. 5.

Symbol	Parameter	Conditions	Т	_{amb} = 25 ^c	C.	T _{an}	_{nb} = o +85 °C	T _{ar} -40 °C to	_{nb} =) +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 5 p	F				•					
t _{pd}	propagation	nA to nY; see Fig. 3 [2]								
	delay	V _{CC} = 0.8 V	-	20.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.8	5.5	10.5	2.5	11.7	2.5	12.9	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	3.9	6.1	2.0	7.3	2.0	8.1	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.2	4.1	1.7	6.1	1.7	6.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.6	2.6	3.6	1.4	4.3	1.4	4.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.4	2.4	3.1	1.2	3.9	1.2	4.4	ns
t _{en}	enable time	nOE to nY; see Fig. 4 [3]								
		V _{CC} = 0.8 V	-	71.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.8	6.2	12.4	2.6	13.6	2.6	13.6	ns
		V _{CC} = 1.4 V to 1.6 V	2.3	4.2	6.9	2.2	7.4	2.2	7.7	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.3	5.3	1.7	5.9	1.7	6.2	ns
		V _{CC} = 2.3 V to 2.7 V	1.5	2.4	3.6	1.4	3.8	1.4	4.1	ns
		V _{CC} = 3.0 V to 3.6 V	1.3	2.0	2.9	1.2	3.2	1.2	3.4	ns
t _{dis}	disable time	nOE to nY; see Fig. 4 [4]								
		V _{CC} = 0.8 V	-	10.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	2.6	4.2	6.2	2.9	6.4	2.9	6.5	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	3.2	4.4	2.2	4.6	2.2	4.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.1	3.1	4.4	1.7	4.6	1.7	4.8	ns
		V _{CC} = 2.3 V to 2.7 V	1.7	2.4	3.2	1.4	3.4	1.4	3.6	ns
		V _{CC} = 3.0 V to 3.6 V	2.1	2.8	3.6	1.2	3.7	1.2	3.8	ns

Symbol	Parameter	Conditions	T	_{amb} = 25 °	,C	T _{an}	_{nb} = o +85 °C	T _{ar} -40 °C to	_{nb} = o +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 10	pF									
t _{pd}	propagation	nA to nY; see Fig. 3 [2]								
	delay	V _{CC} = 0.8 V	-	24.0	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	6.4	12.3	3.0	13.8	3.0	15.2	ns
		V _{CC} = 1.4 V to 1.6 V	2.1	4.5	7.3	1.9	8.5	1.9	9.4	ns
		V _{CC} = 1.65 V to 1.95 V	1.9	3.8	5.5	1.7	6.8	1.7	7.6	ns
		V _{CC} = 2.3 V to 2.7 V	2.1	3.2	4.2	1.6	5.3	1.6	5.9	ns
		V _{CC} = 3.0 V to 3.6 V	1.8	3.0	3.8	1.6	4.6	1.6	5.2	ns
t _{en}	enable time	nOE to nY; see Fig. 4 [3]								
		V _{CC} = 0.8 V	-	75.3	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.2	7.1	14.1	3.0	15.4	3.0	15.4	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.8	8.0	2.1	8.3	2.1	8.6	ns
		V _{CC} = 1.65 V to 1.95 V	1.8	3.9	5.9	1.7	6.5	1.7	6.8	ns
		V _{CC} = 2.3 V to 2.7 V	1.5	2.9	4.2	1.4	4.5	1.4	4.8	ns
		V _{CC} = 3.0 V to 3.6 V	1.4	2.6	3.6	1.3	3.8	1.3	4.0	ns
t _{dis}	disable time	nOE to nY; see Fig. 4 [4]								
		V _{CC} = 0.8 V	-	12.2	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.5	5.3	7.6	3.3	7.9	3.3	7.9	ns
		V _{CC} = 1.4 V to 1.6 V	2.2	4.1	5.6	2.1	5.7	2.1	5.9	ns
		V _{CC} = 1.65 V to 1.95 V	2.4	4.2	5.7	1.7	5.8	1.7	6.0	ns
		V _{CC} = 2.3 V to 2.7 V	1.9	3.2	4.1	1.4	4.3	1.4	4.5	ns
		V _{CC} = 3.0 V to 3.6 V	2.4	4.1	5.0	1.3	5.2	1.3	5.3	ns

Symbol	Parameter	Conditions	T,	T _{amb} = 25 °C			_{nb} = o +85 °C	T _{an} -40 °C to	_{nb} =) +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 15	pF									
t _{pd}	propagation	nA to nY; see Fig. 3 [2]								
	delay	V _{CC} = 0.8 V	-	27.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	7.2	14.1	3.3	15.8	3.3	17.5	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.1	8.1	2.5	9.8	2.5	10.9	ns
		V _{CC} = 1.65 V to 1.95 V	2.2	4.3	6.3	2.0	7.9	2.0	8.8	ns
		V _{CC} = 2.3 V to 2.7 V	2.0	3.7	4.9	1.8	6.0	1.8	6.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.0	3.5	4.4	1.8	5.4	1.8	6.1	ns
t _{en}	enable time	nOE to nY; see Fig. 4 [3]								
		V _{CC} = 0.8 V	-	79.2	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	3.6	7.8	15.8	3.3	17.1	3.3	17.1	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.4	8.8	2.9	9.4	2.9	9.7	ns
		V _{CC} = 1.65 V to 1.95 V	2.1	4.3	6.7	2.0	7.3	2.0	7.7	ns
		V _{CC} = 2.3 V to 2.7 V	1.8	3.4	4.8	1.7	5.2	1.7	5.6	ns
		V _{CC} = 3.0 V to 3.6 V	1.6	3.1	4.1	1.5	4.5	1.5	4.7	ns
t _{dis}	disable time	nOE to nY; see Fig. 4 [4]								
		V _{CC} = 0.8 V	-	14.9	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.3	6.4	8.5	3.7	9.3	3.7	9.4	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	5.0	6.6	2.5	6.9	2.5	7.0	ns
		V _{CC} = 1.65 V to 1.95 V	3.1	5.4	6.6	2.0	7.4	2.0	7.5	ns
		V _{CC} = 2.3 V to 2.7 V	2.4	4.0	5.0	1.7	5.1	1.7	5.5	ns
		V _{CC} = 3.0 V to 3.6 V	3.2	5.3	6.2	1.5	6.7	1.5	6.9	ns

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Symbol	Parameter	Conditions	T _{amb} = 25 °C		T _{amb} = -40 °C to +85 °C		T _{amb} = -40 °C to +125 °C		Unit	
			Min	Typ[1]	Max	Min	Max	Min	Max	
C _L = 30	pF									
t _{pd}	propagation	nA to nY; see Fig. 3 [2]								
	delay	V _{CC} = 0.8 V	-	37.4	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.8	9.5	18.7	4.4	21.4	4.4	24.0	ns
		V _{CC} = 1.4 V to 1.6 V	4.0	6.7	10.8	3.0	13.0	3.0	14.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.9	5.6	8.4	2.6	10.3	2.6	11.5	ns
		V _{CC} = 2.3 V to 2.7 V	2.7	4.8	6.3	2.5	7.8	2.5	8.7	ns
		V _{CC} = 3.0 V to 3.6 V	2.7	4.6	5.8	2.5	7.0	2.5	8.3	ns
t _{en}	enable time	nOE to nY; see Fig. 4 [3]								
		V _{CC} = 0.8 V	-	90.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	4.7	10.0	20.4	4.3	22.0	4.3	22.0	ns
		V _{CC} = 1.4 V to 1.6 V	3.0	6.9	11.3	3.7	12.0	3.7	12.5	ns
		V _{CC} = 1.65 V to 1.95 V	2.6	5.6	8.6	3.2	9.5	3.2	10.1	ns
		V _{CC} = 2.3 V to 2.7 V	2.3	4.5	6.3	2.9	6.8	2.9	7.3	ns
		V _{CC} = 3.0 V to 3.6 V	2.2	4.2	5.8	2.7	6.4	2.7	6.7	ns
t _{dis}	disable time	nOE to nY; see Fig. 4 [4]								
		V _{CC} = 0.8 V	-	51.6	-	-	-	-	-	ns
		V _{CC} = 1.1 V to 1.3 V	6.0	9.8	13.6	4.7	14.3	4.7	14.4	ns
		V _{CC} = 1.4 V to 1.6 V	4.5	7.7	10.5	3.0	10.7	3.0	11.0	ns
		V _{CC} = 1.65 V to 1.95 V	5.2	8.8	11.4	2.6	11.5	2.6	11.6	ns
		V _{CC} = 2.3 V to 2.7 V	3.9	6.4	7.4	2.3	9.0	2.3	10.2	ns
		V _{CC} = 3.0 V to 3.6 V	5.5	9.0	10.7	2.2	10.8	2.2	12.0	ns
C _L = 5 p	F, 10 pF, 15 p	F and 30 pF			•					•
C _{PD}	power dissipation capacitance	output enabled; f _i = 1 MHz; [5] V _I = GND to V _{CC}								
		V _{CC} = 0.8 V	-	2.7	-	-	-	-	-	pF
		V _{CC} = 1.1 V to 1.3 V	-	2.8	-	-	-	-	-	рF
		V _{CC} = 1.4 V to 1.6 V	-	2.9	-	-	-	-	-	pF
		V _{CC} = 1.65 V to 1.95 V	-	3.0	-	-	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V	-	3.6	-	-	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V	-	4.2	-	-	-	-	-	pF
		1							1	

- [1] All typical values are measured at nominal V_{CC} .
- t_{pd} is the same as t_{PLH} and t_{PHL} .
- t_{en} is the same as t_{PZH} and t_{PZL}.
- [4] t_{dis} is the same as t_{PHZ} and t_{PLZ}.
 [5] C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

 $P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

f_i = input frequency in MHz;

f_o = output frequency in MHz;

C_L = output load capacitance in pF;

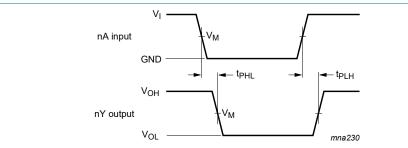
V_{CC} = supply voltage in V;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

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11.1. Waveforms and test circuit



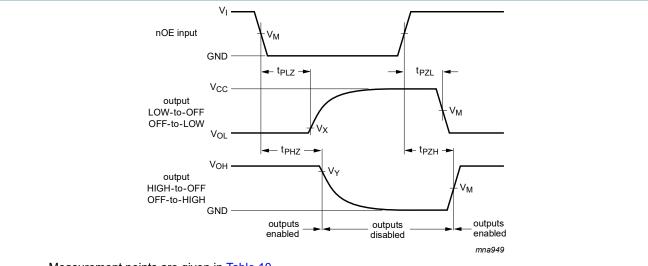
Measurement points are given in Table 9.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 3. The data input (nA) to output (nY) propagation delays

Table 9. Measurement points

Supply voltage	Input	Output		
V _{CC}	V _M	V _I	$t_r = t_f$	V _M
0.8 V to 3.6 V	0.5 × V _{CC}	V _{CC}	≤ 3.0 ns	0.5 × V _{CC}



Measurement points are given in <u>Table 10</u>.

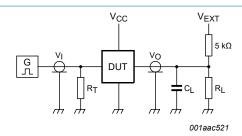
Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Fig. 4. Enable and disable times

Table 10. Measurement points

Supply voltage	Input	Output			
V _{CC}	V _M	V _M	V_X	V _Y	
0.8 V to 1.6 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{OL} + 0.1 V	V _{OH} - 0.1 V	
1.65 V to 2.7 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{OL} + 0.15 V	V _{OH} - 0.15 V	
3.0 V to 3.6 V	0.5 × V _{CC}	0.5 × V _{CC}	V _{OL} + 0.3 V	V _{OH} - 0.3 V	

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Test data is given in Table 11.

Definitions for test circuit:

R_L = Load resistance;

C_L = Load capacitance including jig and probe capacitance;

 R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator;

 V_{EXT} = External voltage for measuring switching times.

Fig. 5. Test circuit for measuring switching times

Table 11. Test data

Supply voltage	Load		V _{EXT}		
V _{CC}	CL	R _L [1]	t _{PLH} , t _{PHL}	t _{PZH} , t _{PHZ}	t _{PZL} , t _{PLZ}
0.8 V to 3.6 V	5 pF, 10 pF, 15 pF and 30 pF	5 kΩ or 1 MΩ	open	GND	2 × V _{CC}

[1] For measuring enable and disable times R_L = 5 k Ω . For measuring propagation delays, set-up and hold times and pulse width R_L = 1 M Ω .

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12. Package outline

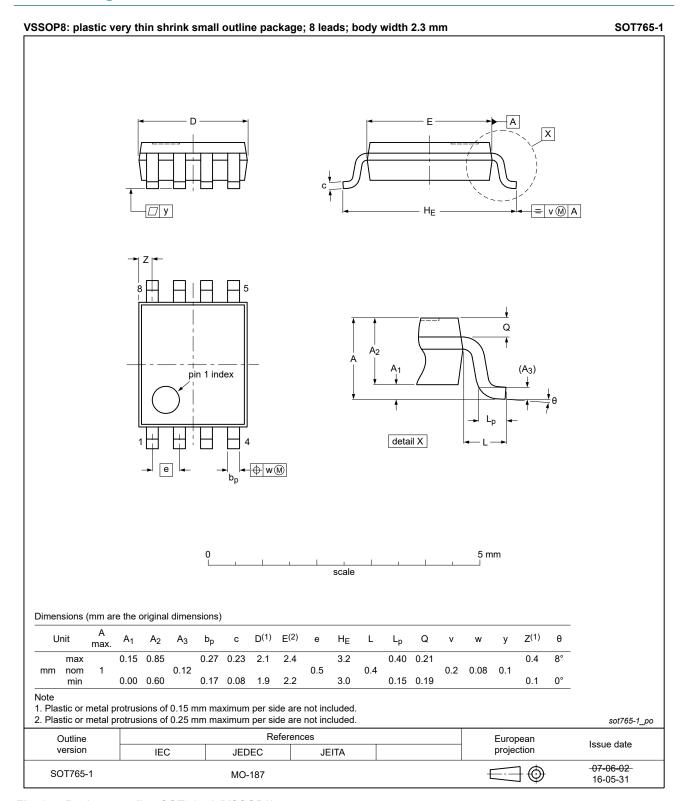


Fig. 6. Package outline SOT765-1 (VSSOP8)

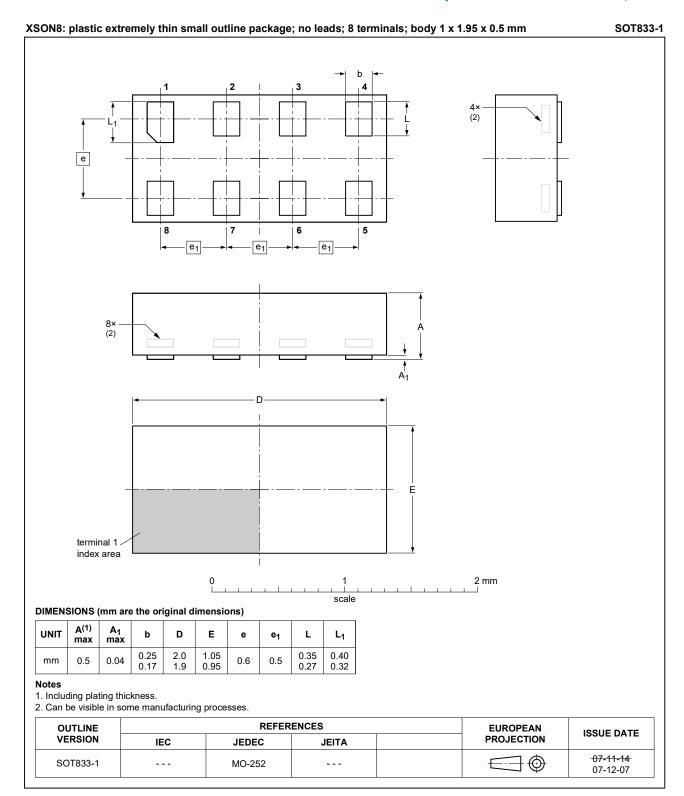


Fig. 7. Package outline SOT833-1 (XSON8)

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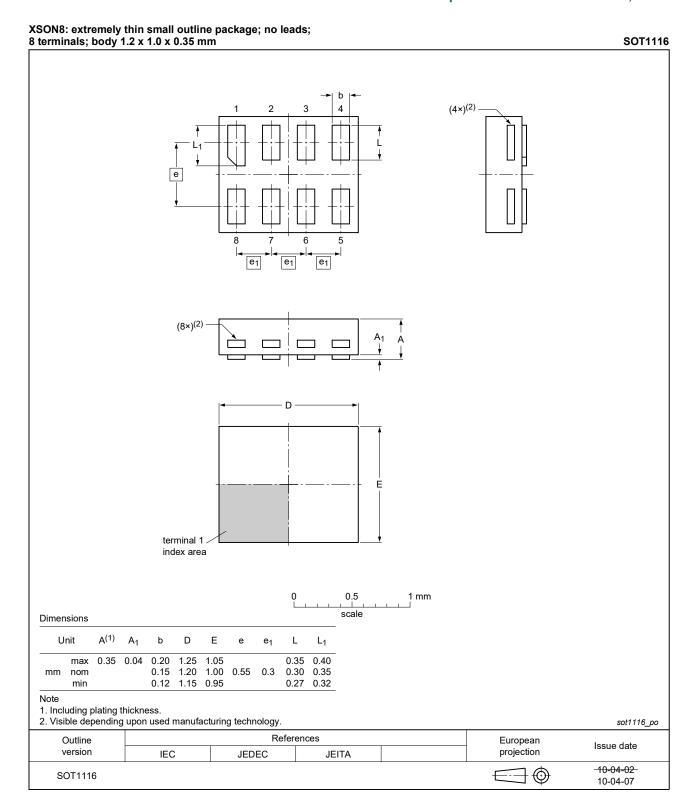


Fig. 8. Package outline SOT1116 (XSON8)

Product data sheet

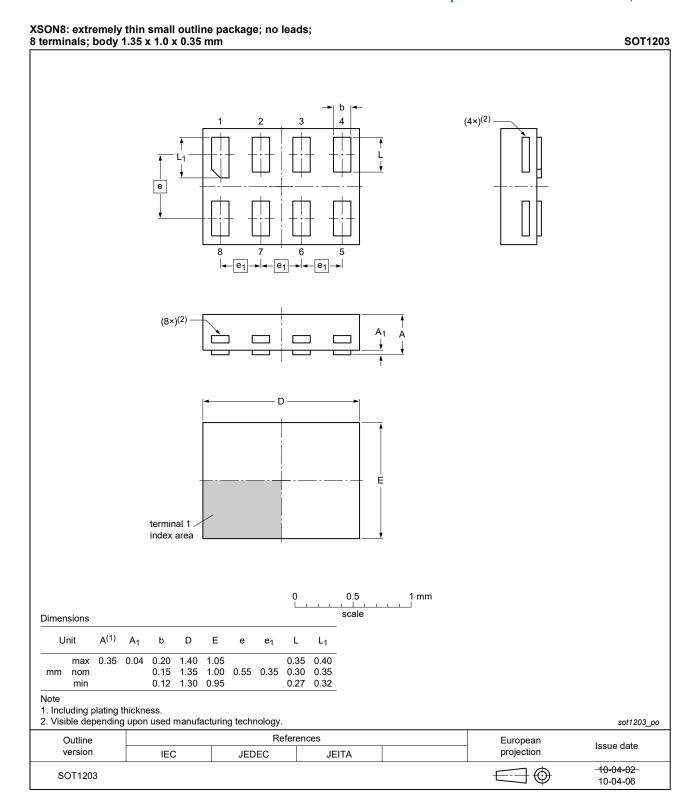


Fig. 9. Package outline SOT1203 (XSON8)

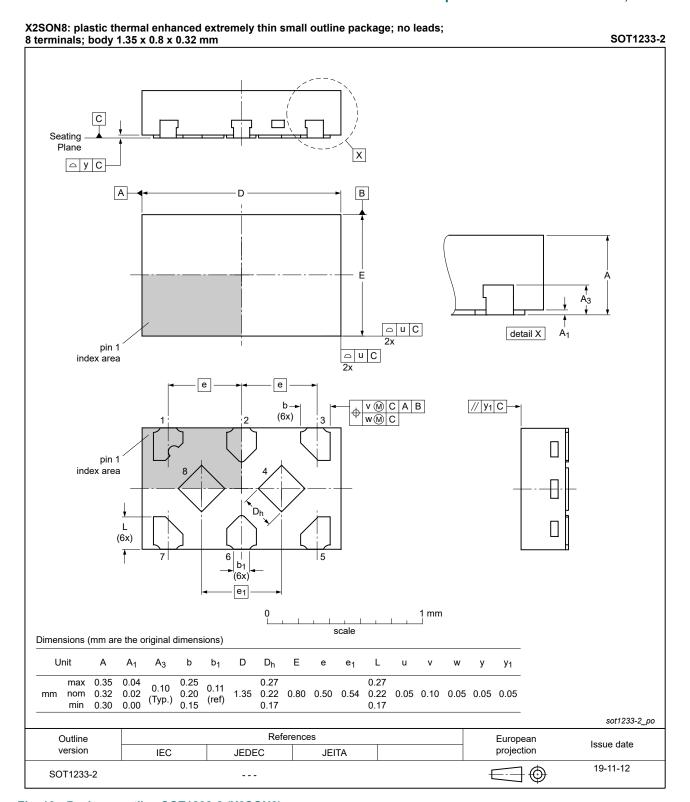


Fig. 10. Package outline SOT1233-2 (X2SON8)

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13. Abbreviations

Table 12. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model

14. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
74AUP2G126 v.15	20240506	Product data sheet	-	74AUP2G126 v.14			
Modifications:	Type numb	Type number 74AUP2G126GF (SOT1089/XSON8) removed.					
74AUP2G126 v.14	20230726	Product data sheet	-	74AUP2G126 v.13			
Modifications:	Section 2: I	ESD specification updated according to the latest JEDEC standard.					
74AUP2G126 v.13	20220621	Product data sheet	- 74AUP2G126 v.12				
Modifications:	Package So	OT1233 (X2SON8) chang	ed to SOT1233-2 (X2SON8).			
74AUP2G126 v.12	20220310	Product data sheet	-	74AUP2G126 v.11			
Modifications:	Section 1 a	er 74AUP2G126GM (SOT nd <u>Section 2</u> updated. rating values for P _{tot} total	,				
74AUP2G126 v.11	20170703	Product data sheet	-	74AUP2G126 v.10			
	guidelines of Legal texts Section 6.1	of this data sheet has been of Nexperia. have been adapted to the and Fig. 10 (drawings SC er 74AUP2G126GD removed.)	new company nar ງT1233/X2SON8) ເ	me where appropriate.			
74AUP2G126 v.10	20161028	Product data sheet	-	74AUP2G126 v.9			
Modifications:	 Added type 	number 74AUP2G126GX	(SOT1233/X2SO	N8)			
74AUP2G126 v.9	20130211	Product data sheet	-	74AUP2G126 v.8			
Modifications:	For type nu	mber 74AUP2G126GD X	SON8U has chang	ed to XSON8.			
74AUP2G126 v.8	20120606	Product data sheet	-	74AUP2G126 v.7			
74AUP2G126 v.7	20111201	Product data sheet	-	74AUP2G126 v.6			
74AUP2G126 v.6	20100621	Product data sheet	-	74AUP2G126 v.5			
74AUP2G126 v.5	20090202	Product data sheet	-	74AUP2G126 v.4			
74AUP2G126 v.4	20090114	Product data sheet	-	74AUP2G126 v.3			
74AUP2G126 v.3	20080409	Product data sheet	-	74AUP2G126 v.2			
74AUP2G126 v.2	20070515	Product data sheet	-	74AUP2G126 v.1			
74AUP2G126 v.1	20061009	Product data sheet	-	-			

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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- [2] The term 'short data sheet' is explained in section "Definitions".
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